



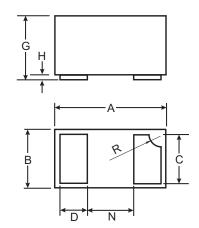
SURFACE MOUNT SCHOTTKY BARRIER DIODE

Features

- Low Forward Voltage Drop
- Fast Switching
- Ultra-Small Leadless Surface Mount Package
- PN Junction Guard Ring for Transient and ESD Protection
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: DFN1006-2
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: Cathode Dot
- Terminals: Finish NiPdAu annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Ordering Information: See Page 2
- Marking Code: 43, Dot Denotes Cathode Side
- Weight: 0.001 grams



DFN1006-2				
Dim	Min Max Ty		Тур	
Α	0.95	1.075	1.00	
В	0.55	0.675	0.60	
С	0.45	0.55	0.50	
D	0.20	0.30	0.25	
G	0.47	0.53	0.50	
Н	0	0.05	0.03	
N	_	_	0.40	
R	0.05	0.15	0.10	
All Dimensions in mm				

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RM} V _{RWM} V _R	40	V
Forward Continuous Current	I _{FM}	200	mA
Forward Surge Current @ t < 1.0	s I _{FSM}	600	mA
Operating Temperature Range	Tj	-55 to +125	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C

Thermal Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation	P _d	250	mW
Thermal Resistance, Junction to Ambient Air	$R_{\theta JA}$	400	°C/W

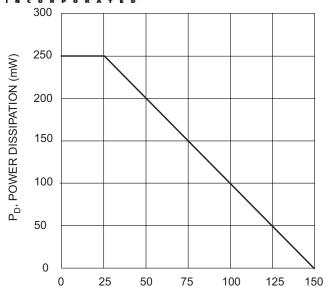
Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 3)	V _{(BR)R}	40	_	_	V	$I_R = 10\mu A$
Forward Voltage (Note 3)	VF		_	380 1000	mV	$t_p < 300 \mu s, I_F = 1.0 mA$ $t_p < 300 \mu s, I_F = 40 mA$
Reverse Leakage Current (Note 3)	I _R	_	20	200	nA	$t_p < 300 \mu s, V_R = 30 V$
Total Capacitance	Ст	_	2.3	5.0	pF	$V_R = 0V$, $f = 1.0MHz$
Reverse Recovery Time	t _{rr}	_	_	5.0	ns	$I_F = I_R = 10$ mA to $I_R = 1.0$ mA, $R_L = 100\Omega$

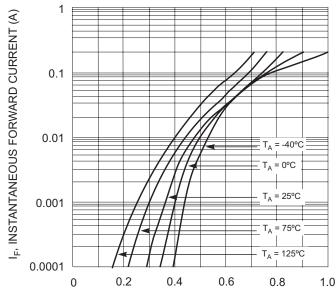
Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 3. Short duration pulse test used to minimize self-heating effect.

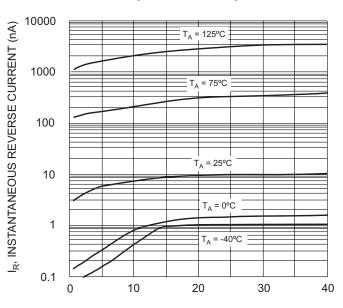




T_A, AMBIENT TEMPERATURE (°C) Fig. 1 Power Derating Curve



 $V_{\rm F}$, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Voltage



 V_{R} , INSTANTANEOUS REVERSE VOLTAGE (V) Fig. 3 Typical Reverse Characteristics

Ordering Information (Note 4)

Device	Packaging	Shipping
BAS40LP-7	DFN1006-2	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

• 43

43 = Product Type Marking Code, Dot Denotes Cathode Side



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